NSN 5961-01-223-8457

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-223-8457 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-71 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.071 inches **Features Provided:** Hermetically sealed case and quality assurance level txv **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 drain to gate voltage all transistor **Current Rating Per Characteristic:** 30.00 milliamperes gate current all transistor **Power Rating Per Characteristic:** 400.0 milliwatts total power dissipation all transistor **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 6 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/430 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Fiig: A110a0

Yes - demil/mli